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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
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10/719,065

11/24/2003

Johannes Catharinus Hubertus Mulkens

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11/29/2007

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MCLEAN, VA 22102

EXAMINER

KIM, PETER B

ART UNIT

PAPER NUMBER

2851

MAIL DATE

DELIVERY MODE

11/29/2007

PAPER

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

Office Action Summary

Application No.

10/719,065

Applicant(s)

HUBERTUS MULKENS ET AL.

Examiner

Peter B. Kim

Art Unit

2851

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

- 1) ☒ Responsive to communication(s) filed on 06 August 2007.
- 2a) ☒ This action is **FINAL**. 2b) ☐ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

- 4) ☒ Claim(s) 1-11, 13-55 and 62 is/are pending in the application.
- 4a) Of the above claim(s) _____ is/are withdrawn from consideration.
- 5) ☐ Claim(s) _____ is/are allowed.
- 6) ☒ Claim(s) 1-11, 13-55 and 62 is/are rejected.
- 7) ☐ Claim(s) _____ is/are objected to.
- 8) ☐ Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☐ The drawing(s) filed on _____ is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

Priority under 35 U.S.C. § 119

- 12) ☒ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☒ All b) ☐ Some * c) ☐ None of:
1. ☐ Certified copies of the priority documents have been received.
 2. ☒ Certified copies of the priority documents have been received in Application No. 09/866,875.
 3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

* See the attached detailed Office action for a list of the certified copies not received.

Attachment(s)

- | | |
|--|---|
| 1) <input checked="" type="checkbox"/> Notice of References Cited (PTO-892) | 4) <input type="checkbox"/> Interview Summary (PTO-413)
Paper No(s)/Mail Date. _____ |
| 2) <input type="checkbox"/> Notice of Draftsperson's Patent Drawing Review (PTO-948) | 5) <input type="checkbox"/> Notice of Informal Patent Application |
| 3) <input type="checkbox"/> Information Disclosure Statement(s) (PTO/SB/08)
Paper No(s)/Mail Date _____ | 6) <input type="checkbox"/> Other: _____ |

DETAILED ACTION

Applicant's arguments filed on Aug. 6, 2007 have been fully considered.

Claim Rejections - 35 USC § 112

The following is a quotation of the first paragraph of 35 U.S.C. 112:

The specification shall contain a written description of the invention, and of the manner and process of making and using it, in such full, clear, concise, and exact terms as to enable any person skilled in the art to which it pertains, or with which it is most nearly connected, to make and use the same and shall set forth the best mode contemplated by the inventor of carrying out his invention.

Claims 26-49, and 52-55 are rejected under 35 U.S.C. 112, first paragraph, as failing to comply with the written description requirement. The claim(s) contains subject matter which was not described in the specification in such a way as to reasonably convey to one skilled in the relevant art that the inventor(s), at the time the application was filed, had possession of the claimed invention.

Regarding claims 26, 52, 54, and 55, it seems that added limitation of measuring the amount of interaction of the beam of radiation with the region of gas out of a path of the beam of radiation is a new matter. It seems the specification as filed only discloses measuring the amount of interaction of the beam of radiation with the region of gas in the path of the beam of radiation. It does not seem to disclose the interaction of the beam with the region of gas out of a path of the beam of radiation.

The following is a quotation of the second paragraph of 35 U.S.C. 112:

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.

Claims 26-49, and 52-55 are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

Regarding claims 26, 52, 54, and 55, the newly added language is confusing because it is not clear if the measurement is taken out of a path of the beam or radiation or if the interaction of the beam takes place with the region of gas out of a path of the beam of radiation.

The remaining claims, not specifically mentioned, are rejected for incorporating the defects from the base claim by dependency.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

Claims 26-34, 36, 39, 41, 43, 44, 47, 48, and 52-55 are rejected under 35 U.S.C. 103(a) as being unpatentable over Nishi (6,545,746) in view of Nishinaga (2003/0025890).

Regarding claims 26, 28, 34, 47, 48, 52-54 and 55, Nishi discloses a lithographic projection apparatus and a device manufacturing method comprising a radiation system (111) a support structure (112) for supporting a patterning structure, a substrate table (114), a projection system (113) and a radiation absorber comprising a gas supply to supply an absorbent gas at a controlled concentration in the evacuated optical path (col. 35, line 56 – col. 36, line 47), the absorbent gas absorbing radiation energy by increasing gas pressure (col. 35, line 56 – col. 36,

line 47) to absorb radiation during exposure of the radiation sensitive material to the patterned beam to adjust one of: radiation power emitted by a radiation source configured to supply radiation to the radiation system; the uniformity of energy of the beam of radiation perpendicular to an optical axis of the apparatus; radiation energy of pulses of radiation emitted by the radiation source; duration of an exposure of a target portion; angular distribution of the radiation energy delivered by the beam of radiation (col. 35, line 55-60).

Regarding claims 27, 41 and 43, Nishi discloses the radiation-energy detector or sensor located proximate one of a pupil plane, a plane of patterning structure, a plane of the substrate; a conjugate plane of the pupil plane; a conjugate plane of the patterning structure plane; and a conjugate plane of the substrate plane (Fig. 1 and 8, col. 17, lines 32-42, col. 28, lines 8-14). Regarding claim 31, Nishi discloses the radiation-energy detector comprising an enclosure surrounding at least one volume and transparent to beam of radiation (Fig. 8 and 9, col. 28, lines 9-65, col. 32, line 46 – col. 34, line 60). Regarding claims 32 and 33, the projection system of Nishi discloses a first aperture to allow radiation to enter and a second aperture to allow radiation to exit (Fig. 8, 9, 12 and 13) and the absorption by gas is substantially located at the focal point (col. 32, line 46 – col. 34, line 60, col. 35, line 56 – col. 36, line 47). Regarding claim 36, Nishi also teaches gas extractor (Fig. 9, col. 35, line 56 – col. 36, line 47). Since any gas in an enclosure will eventually reach an equilibrium in concentration, the concentration of the gas in Nishi would be symmetric about the optical axis. Nishi also discloses controlling one of the property of the absorbent gas (col. 36, lines 1-43).

Regarding claims 29, 30, 39 and 44, Nishi discloses the absorbent gas comprising oxygen, helium and nitrogen (col. 36, lines 44-46, col. 45, lines 17-42), mixed with purge gas

(col. 45, lines 17-67), and radiation comprising wavelength less than 365 nm (KrF and ArFcol. 14, lines 6-20), and the detector, which detects ultraviolet light. Nishi discloses radiation-energy detector to determine energy of radiation passing through a region of interactive gas (col. 35, line 56 – col. 36, line 47, in order to control the control the amount of light and to obtain desirable amount, a detector must be provided, thus such detector is inherent to the invention of Nishi). Nishi discloses a concentration controlled volume of radiation absorbent gas to be traversed by the beam of radiation (col. 35, line 56- col. 36, line 47, and col. 45, lines 17-67). Nishi supplies and controls absorbent gas to effect a desired non-uniform attenuation (col. 35, line 56- col. 63, line 47, and col. 45, lines 17-67). Nishi discloses a device (w) manufactured according to the method above.

However, Nishi does not disclose and a radiation-energy detector or sensor proximate to the enclosure providing an output signal and energy profile that is proportional to an amount of interaction of the projection beam with the absorbent gas. Nishinaga discloses in para 0125 a radiation-energy detector or sensor located out of a path of the beam of radiation. Since controlling the radiation-energy amount on the substrate and to obtaining the amount necessary is important in lithographic apparatus (see Nishi col. 35, line 56 – col. 36, line 47), it would have been obvious to one of ordinary skill in the art at the time of the invention to provide the radiation amount detector as taught by Nishinaga in para 0125 to the invention of Nishi.

Claims 26, 27, 30, 52, 54, and 55 are rejected under 35 U.S.C. 103(a) as being unpatentable over Mori et al. (Mori) (2001/0030740) in view of Nishinaga.

Mori discloses a lithographic projection apparatus and a device manufacturing method comprising a radiation system with wavelength less than 365 nm (10 and para 0044) a support structure (107) for supporting a patterning structure (20), a substrate table (23), a projection system (21) and a radiation-energy detector or sensor (24) proximate to a conjugate plane of the substrate plane (Fig. 1) providing an output signal that is proportional to an amount of interaction of the projection beam with the absorbent gas (Mori discloses in para 0081, inert gas inside the projection system. Since there is some absorption of illumination light with inert gas, the illumination detected by the sensor 24 would provide an output that is proportional to an amount of interaction of the beam of radiation with the region of the gas). However, Mori does not disclose measuring of the beam with the region of gas out of a path of the beam of radiation. Nishinaga discloses measuring the radiation amount out of the path of the beam of radiation (para 0125). Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to provide the sensor of Nishinaga with a beamsplitter to measure the radiation amount out of the path of the beam in order to measure the radiation energy during the exposure.

Claims 26-34, 36-39, 41, 43, 44, 47, 48, and 52-55 are rejected under 35 U.S.C. 103(a) as being unpatentable over Shiozawa (JP-11-354409) in view of Nishinaga.

Regarding claims 26, 28, 34, 47, 48, 52-54 and 55, Shiozawa discloses a lithographic projection apparatus and a device manufacturing method comprising a radiation system (1) a support structure (not shown) for supporting a patterning structure (11), a substrate table (15), a projection system (12) and a radiation absorber comprising a gas supply to supply an absorbent gas at a controlled concentration in the evacuated optical path (Fig. 3, 5 and abstract), the absorbent gas absorbing radiation energy by increasing gas pressure (col. 35, line 56 – col. 36,

line 47) to absorb radiation during exposure of the radiation sensitive material to the patterned beam to adjust one of: radiation power emitted by a radiation source configured to supply radiation to the radiation system; the uniformity of energy of the beam of radiation perpendicular to an optical axis of the apparatus; radiation energy of pulses of radiation emitted by the radiation source; duration of an exposure of a target portion; angular distribution of the radiation energy delivered by the beam of radiation (Fig. 1, 3, abstract, and para 0037, 0038); and a radiation-energy detector or sensor (16) proximate to the enclosure providing an output signal and energy profile that is proportional to an amount of interaction of the projection beam with the absorbent gas (para 0057, abstract).

Regarding claims 27, 41 and 43, Shiozawa discloses the radiation-energy detector or sensor located proximate one of a pupil plane, a plane of patterning structure, a plane of the substrate; a conjugate plane of the pupil plane; a conjugate plane of the patterning structure plane; and a conjugate plane of the substrate plane (Fig. 1, para 0057). Regarding claim 31, Shiozawa discloses the radiation-energy detector comprising an enclosure surrounding at least one volume and transparent to beam of radiation (Fig. 1, 3, 5 and abstract). Regarding claims 32 and 33, the projection system of Shiozawa discloses a first aperture to allow radiation to enter and a second aperture to allow radiation to exit (Fig. 1) and the absorption by gas is substantially located at the focal point (Fig. 1, 3, 5, abstract and para 0060-0062). Regarding claim 36, Shiozawa also teaches gas extractor (Fig. 3, 5, para 0060-0062). Since any gas in an enclosure will eventually reach an equilibrium in concentration, the concentration of the gas in Shiozawa would be symmetric about the optical axis. Shiozawa also discloses controlling one of the property of the absorbent gas by controlling the gas pressure and composition (para 0037, 0038).

Regarding claims 29, 30, 39 and 44, Shiozawa discloses the absorbent gas comprising oxygen (abstract), mixed with purge gas (abstract), and radiation comprising wavelength less than 365 nm (para 0025), and the detector (16), which detects ultraviolet light. Shiozawa discloses radiation-energy detector to determine energy of radiation passing through a region of interactive gas (para 0057). Shiozawa discloses a concentration controlled volume of radiation absorbent gas to be traversed by the beam of radiation (Fig. 1, abstract). Shiozawa supplies and controls absorbent gas to effect a desired non-uniform attenuation (abstract). Shiozawa discloses a device (13) manufactured according to the method above.

Regarding claims 37 and 38, Shiozawa discloses the claimed invention as discussed above. Shiozawa does not disclose that the gas enters the enclosure at a speed ten times the speed of sound. However, it would have been obvious to one having ordinary skill in the art at the time of the invention was made to provide the gas at a speed ten times the speed of sound since it has been held that discovering an optimum value of a result effective variable involves only routine skill in the art. *In re Boesch*, 617 F.2d 272, 205 USPQ 215 (CCPA 1980).

However, Shiozawa does not disclose measuring of the beam with the region of gas out of a path of the beam of radiation. Nishinaga discloses measuring the radiation amount out of the path of the beam of radiation (para 0125). Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to provide the sensor of Nishinaga with a beamsplitter to measure the radiation amount out of the path of the beam in order to measure the radiation energy during the exposure.

Claim 35 is rejected under 35 U.S.C. 103(a) as being unpatentable over Nishi in view of Nishinaga as applied to claim 26 above, and further in view of Tanaka et al. (Tanaka) (2003/0020888).

The further difference between the claimed invention and the modified Nishi is the radiation in the range of 5-20 nm and a detector to detect such radiation. Tanaka discloses providing EUV light to a lithographic apparatus (para 0187). Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to provide EUV light and a detector to detect such light to the invention of Nishi in order to improve the resolution of the exposed pattern.

Claims 45 and 46 are rejected under 35 U.S.C. 103(a) as being unpatentable over Nishi in view of Nishinaga as applied to claim 26 above, and further in view of Kley (6,353,219).

The further difference between the claimed invention and the modified Nishi is the sensor comprises an electrode which is charged at a potential opposite to a charged particle to which it is sensitive. Kley discloses in col. 53, lines 31-56, a radiation energy sensor including an electrode and sensitive to a charged particle which is opposite in sign. Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to provide the sensor of Kley to the invention of Nishi in order to facilitate analysis of the output signal through the controller as taught by Kley in col. 53, lines 15-30.

Claims 1-7, 9-11, 13-17, 20-22, 24, 25, 50, 51 and 62 are rejected under 35 U.S.C. 103(a) as being unpatentable over Shiozawa (JP 11-354409) in view of Nishi et al. (Nishi) (6,414,743).

Regarding claims 1, 2, 6, 7, 13, 14, 24, 25, 50, 51 and 62, Shiozawa discloses, discloses a lithographic projection apparatus and a device manufacturing method comprising a radiation system (1) providing radiation comprising a wavelengths less than 365 nm (para 0025) in evacuated path (Fig. 1) a support structure (not shown) for supporting a patterning structure (11), a substrate table (15), a projection system (12) and a radiation absorber comprising a gas supply to supply an absorbent gas at a controlled concentration (Fig. 3, 5, and abstract) to absorb radiation during exposure of the radiation sensitive material to the patterned beam to adjust one of: radiation power emitted by a radiation source configured to supply radiation to the radiation system; the uniformity of energy of the beam of radiation perpendicular to an optical axis of the apparatus; radiation energy of pulses of radiation emitted by the radiation source; duration of an exposure of a target portion; and angular distribution of the radiation energy delivered by the beam of radiation (Fig. 1, 3, abstract, and para 0037, 0038); and the absorbent gas comprising oxygen (abstract), mixed with purge gas (abstract), and the detector (16), which detects ultraviolet light (para 0025). Shiozawa discloses radiation-energy detector to determine energy of radiation passing through a region of interactive gas (16, para 0057). Shiozawa discloses a concentration controlled volume of radiation absorbent gas to be traversed by the beam of radiation (abstract). Shiozawa supplies and controls absorbent gas to effect a desired non-uniform attenuation (abstract).

Regarding claims 3, 17 and 19, Shiozawa discloses the radiation absorber located proximate one of a pupil plane, a plane of patterning structure, a plane of the substrate; a conjugate plane of the pupil plane; a conjugate plane of the patterning structure plane; and a conjugate plane of the substrate plane (Fig. 1, 3, 5, abstract). Regarding claim 4, Shiozawa

discloses absorber comprising an enclosure surrounding at least one volume and transparent to beam of radiation (Fig. 1, 3, 5, abstract). Regarding claim 5, the projection system of Shiozawa discloses a first aperture to allow radiation to enter and a second aperture to allow radiation to exit (Fig. 1, 3, 5 abstract). Regarding claim 9, Shiozawa teaches gas extractor (Fig. 3, 5, para 0060-0062). Regarding claim 15 and 16, since any gas in an enclosure will eventually reach an equilibrium in concentration, the concentration of the gas in 822 would be symmetric about the optical axis. Regarding claims 21 and 22, Shiozawa discloses controlling one of the property of the absorbent gas by controlling the gas pressure and composition (para 0037, 0038). Regarding claims 10 and 11, Shiozawa does not disclose that the gas enters the enclosure at a speed ten times the speed of sound. However, it would have been obvious to one having ordinary skill in the art at the time of the invention was made to provide the gas at a speed ten times the speed of sound since it has been held that discovering an optimum value of a result effective variable involves only routine skill in the art. *In re Boesch*, 617 F.2d 272, 205 USPQ 215 (CCPA 1980).

However, Shiozawa does not disclose that the absorbent gas comprises one of water or hydrocarbons. Nishi discloses in col. 19, line 50 – col. 20, line 3, that oxygen as well as water and hydrocarbon absorb radiation. Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to provide water or hydrocarbon instead of oxygen as absorbent gas because water and hydrocarbon are known to have the same desired properties as oxygen and it would make an appropriate substitute.

Double Patenting

The nonstatutory double patenting rejection is based on a judicially created doctrine grounded in public policy (a policy reflected in the statute) so as to prevent the unjustified or improper timewise extension of the “right to exclude” granted by a patent and to prevent possible harassment by multiple assignees. A nonstatutory obviousness-type double patenting rejection is appropriate where the conflicting claims are not identical, but at least one examined application claim is not patentably distinct from the reference claim(s) because the examined application claim is either anticipated by, or would have been obvious over, the reference claim(s). See, e.g., *In re Berg*, 140 F.3d 1428, 46 USPQ2d 1226 (Fed. Cir. 1998); *In re Goodman*, 11 F.3d 1046, 29 USPQ2d 2010 (Fed. Cir. 1993); *In re Longi*, 759 F.2d 887, 225 USPQ 645 (Fed. Cir. 1985); *In re Van Ornum*, 686 F.2d 937, 214 USPQ 761 (CCPA 1982); *In re Vogel*, 422 F.2d 438, 164 USPQ 619 (CCPA 1970); and *In re Thorington*, 418 F.2d 528, 163 USPQ 644 (CCPA 1969).

A timely filed terminal disclaimer in compliance with 37 CFR 1.321(c) or 1.321(d) may be used to overcome an actual or provisional rejection based on a nonstatutory double patenting ground provided the conflicting application or patent either is shown to be commonly owned with this application, or claims an invention made as a result of activities undertaken within the scope of a joint research agreement.

Effective January 1, 1994, a registered attorney or agent of record may sign a terminal disclaimer. A terminal disclaimer signed by the assignee must fully comply with 37 CFR 3.73(b).

Claims 1-7, 9, 13, 15-19, 21-26, 29, 31-34, 36, 39, 40-43, 47-55, and 62 are rejected on the ground of nonstatutory obviousness-type double patenting as being unpatentable over claims 1, 2, and 5-23 of U.S. Patent No. 6,538,716 (“716”). Although the conflicting claims are not identical, they are not patentably distinct from each other because the current claims are broader and thus fully met by the prior patent. For example, 716 also claims a gas composition sensor which is not claimed in the current claims.

Claims 8, 14, 30 and 35 are rejected on the ground of nonstatutory obviousness-type double patenting as being unpatentable over claims 1, 5, 7, and 19 of U.S. Patent No. 6,538,716 (716) in view of Tanaka et al. (Tanaka). As indicated above 716 claims to an invention not patentably distinct from the current claims; however, 716 does not claim radiation in the range of 5-20 nm and in the range of less than 365 nm and a detector to detect such radiation. Tanaka

discloses providing EUV light and ArF and KrF laser to a lithographic apparatus (para 0187). Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to provide EUV light and ArF and KrF a detector to detect such light to the claims of 716 in order to improve the resolution of the exposed pattern.

Response to Arguments

In response to applicant's arguments the rejection based on 35 USC 112 2nd paragraph is withdrawn.

Applicant argues that Nishi (6,545,746) does not inherently disclose the radiation-energy detector. Nishi discloses in col. 35, lines 55-60, "light quantity control method according to this embodiment will be described below." Nishi also discloses in col. 36, lines 9-16, "the illuminating light IL, to be continuously controlled in a predetermined range", and in the same section, Nishi teaches reducing or increasing the amount of illuminating lighting. In order to continuously control the light and to determine that the amount of lighting must be increased or decreased required a radiation-energy detector. Without a detector, Nishi would not be able to determine whether the amount of lighting must be increased or decreased. In order to control the lighting, a detector is required.

Applicant uses an analogy of a water tap to argue that Nishi does not suggest a radiation-energy detector. Applicant argues that to "control the amount of water flowing through a tap, no detector of water is required, rather only the valve needs to be opened or closed." The analogy would be valid if Nishi did not teach a lithographic projection exposure apparatus. But in the context of a lithographic projection exposure apparatus of Nishi, accurate detection of radiation-

energy is required because radiation energy below or above required value would deteriorate the quality of the image exposed on the substrate.

It would be more appropriate to extend applicant's analogy by requiring that water from the tap is used to fill a container exactly half way not a drop below or a drop above the half way mark. When the valve is opened, detector is needed to see how much water is in the container and how fast the water is filling the container, in order to control the amount of the water coming out of the tap in order to precisely obtain a half-filled container. Similarly in Nishi, a detector is required to control the amount of light. Further, Nishi discloses in col. 17, lines 32-42, a detector to detect amount of light reflected from the substrate. Therefore, it would be obvious to provide the detector of Nishinaga to the invention of Nish.

Applicant also argues that it is more likely that Nishi discloses a pressure detector. However, it seems that since the control of the light so that a predetermined amount of light reaches the substrate (col. 35, lines 49-55), it seems that rather than a pressure detector, a radiation detector is required.

Regarding Mori and Shiozawa references, in response to applicant's arguments, the rejections are modified by combining with Nishigawa.

Applicant argues that Shiozawa reference does not teach the absorbent gas comprising one of water or hydrocarbon, and that Nishi's teaching does not suggest substituting the oxygen of Shiozawa with the water or hydrocarbon. Shiozawa teaches using oxygen with interacts with the radiation to control the amount of the radiation. Nishi teaches that water and hydrocarbon also interacts with radiation to affect the amount of radiation. It seems that since Shiozawa's purpose of using oxygen is because of its property of readily absorbing or interacting with the

radiation beam, it would be obvious to replace oxygen with other gases, which comprise water or hydrocarbon, with the similar property. Applicant argues that Nishi teaches that water and hydrocarbon are undesirable because the purpose of Nishi reference is to clear the path of the beam of gases which interact with the radiation beam. However, Nishi is not relied for the teaching of cleaning of the radiation beam path, but the teaching that water and hydrocarbon have the similar property as oxygen which is the ability to absorb or interact with the radiation beam.

Regarding the double patenting rejection, as applicant traverses the rejection for similar reasons as provided in the applicant's previous response, the response from the previous office action is repeated. Applicant's arguments are unclear because the rejection clearly states that the claims of the current application are broader because the claims of the previous patent includes all of the limitation of the current claims and also includes a limitation which is not claimed in the current application. For example, claims 1 and 19 of the previous patent claim projection apparatus and a device manufacturing method comprising a radiation system, a support structure to support patterning structure, a substrate table, a projection system, and a radiation control mechanism responsive to gas composition to control the radiation energy, which is radiation absorber of claim 1 in the current application. Further, claim 5 of the previous patent claims an energy sensor, and claim 22 of the previous patent claims absorber gas of hydrocarbons. Claim 1 and 19 of the previous patent is narrower because those claims have a limitations not found in the claims of the current application, which is a gas composition sensor. Thus, the claims of the current application are broader and thus fully met by the prior patent.

Conclusion

Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

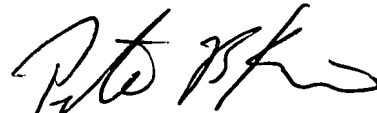
Any inquiry concerning this communication or earlier communications from the examiner should be directed to Peter B. Kim whose telephone number is (571) 272-2120. The examiner can normally be reached on 9:00 AM - 6:30 PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Diane Lee can be reached on (571) 272-2399. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.



Peter B. Kim
Primary Examiner
Art Unit 2851

November 15, 2007